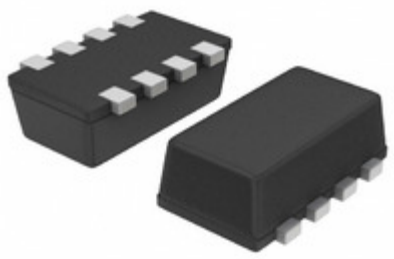


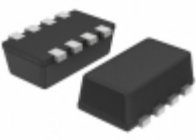


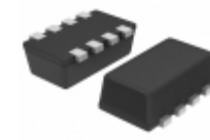


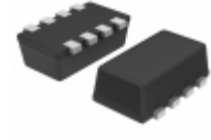
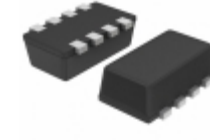
	<h2 style="color: red;">NTHD3101FT1G</h2>
	<p>Hersteller-Teilenummer: NTHD3101FT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 3.2A CHIPFET</p> <p>Datenblätter:  NTHD3101FT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 312411 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTHD3101FT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 20V 3.2A CHIPFET
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	312411 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SMD, Flat Lead
Supplier Device-Gehäuse	ChipFET™
Verlustleistung (max)	1.1W (Ta)
Typ FET	P-Channel
FET-Merkmal	Schottky Diode (Isolated)
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3.2A (Tj)
Rds On (Max) @ Id, Vgs	80 mOhm @ 3.2A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	7.4nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	680pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs (Max)	±8V
Verpackung	Tape & Reel (TR)



NTHD3101FT1G ist neu im Original, Suche NTHD3101FT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTHD3101FT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTHD3101FT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTHD3101FT3G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 3.2A CHIPFET</p>	 <p>NTHD3103FT1G ON NTHD3103FT1G ON</p>	 <p>NTHD3101FT1 ON NTHD3101FT1 ON</p>	 <p>NTHD3100CT3 AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V CHIPFET</p>
 <p>NTHD3102CT1G AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V 4A/3.1A 1206A</p>	 <p>NTHD3100CT1G AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V CHIPFET</p>	 <p>NTHD3100CT3G AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V CHIPFET</p>	 <p>NTHD3100CT1 AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V CHIPFET</p>

heiße Teile

Mehr

 NTH05HC-32.768	 NTH08HB3-30.000	 NTHA8HC-60.000	 NTHC5513T1	 NTHC5513T1G
 NTHD2102PT1	 NTHD2102PT1G	 NTHD3100CT1	 NTHD3101FT1	 NTHD3102CT1G
 NTHD310FT1G	 NTHD3133PFT1G	 NTHD4102PT1	 NTHD4102PT1G	 NTHD4401PT1G
 NTHD4401PT3G	 NTHD4502NT1	 NTHD4502NT1G	 NTHD4508NT1	 NTHD4508NT1G
 NTHD4N02FT1	 NTHD4N02FT1G	 NTHD4P02FT1	 NTHD4P02FT1-D	 NTHD4P02FT1G
 NTHD5902	 NTHD5902T1	 NTHD5903T1	 NTHD5903T1G	 NTHD5904N
 NTHD5904NT1	 NTHD5904NT1G	 NTHD5905T1	 NTHD5905T1G	 NTHS0402N02N1002HE
 NTHS0603N01N1003JE	 NTHS0603N02N6801	 NTHS0603N02N6801JE	 NTHS0805N01N5002JE	 NTHS1206N01N4702JE
 NTHS1206N02N1002JR	 NTHS1206N02N1002KR	 NTHS2101PT1	 NTHS2101PT1G	 NTHS4101PT1
 NTHS4101PT1G	 NTHS4111PT1	 NTHS4166NT1G	 NTHS4501NT1	 NTHS4501NT1G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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